

10/688,965

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	15	((cf4 sf6 nf3 chf3) near4 dielectric) same etch\$3) and @ad<"20030730"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 11:47
L2	569	((polysilicon (polycrystalline adj silicon)) near6 (oxide residue)) same (hbr o2 n2 cl2) and @ad<"20030730"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 11:51
L3	461	2 and gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 11:50
L4	274	((polysilicon (polycrystalline adj silicon)) near6 (oxide residue)) same ((hbr o2 n2 cl2) near4 etch\$3)) and @ad<"20030730"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 11:55
L5	214	4 and gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 11:52
L6	0	((polysilicon (polycrystalline adj silicon)) near6 (natural adj oxide)) same ((hbr o2 n2 cl2) near4 etch\$3)) and @ad<"20030730"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 11:57
L7	9	((polysilicon (polycrystalline adj silicon)) near6 (natural adj oxide)) and ((hbr o2 n2 cl2) near4 etch\$3) and @ad<"20030730"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 12:19
L8	95	((polysilicon (polycrystalline adj silicon)) near6 residue) and ((hbr o2 n2 cl2) near4 etch\$3) and @ad<"20030730"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 12:21
L9	28	((polysilicon (polycrystalline adj silicon)) near6 residue) same ((hbr o2 n2 cl2) near4 etch\$3)) and @ad<"20030730"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 12:21
S1	2	("5185279").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/05/23 11:32

S2	907	(semiconductor ic (integrated adj circuit) die dice chip) and @ad<"20030730" and (gate near5 (electrode terminal)) and (etch\$3 near4 (hbr (hydrogen adj bromide)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/20 18:37
S3	269	((polysilicon (polycrystalline adj silicon)) near5 (hbr n2 cf4 nf3 chf3)) and @ad<"20030730" and (etch\$ near4 second)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/20 18:40
S4	242	S3 and gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/20 18:41